

SPECIFICATION

Device Name : IGBT Module

Type Name : 7MBR35SB120-01

Spec. No. : MS6M 0554

Date : Jun. - 02 - 2000

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Fuji Electric Co., Ltd.
Matsumoto Factory

	DATE	NAME	APPROVED	Fuji Electric Co., Ltd.			
DRAWN	Jun. - 2 - '00	T. Kobayashi	<i>T. Kobayashi</i>	DWG. NO.	MS6M 0554	1 / 10	Q
CHECKED	June - 2 - 00	S. Matsu					

Revised Records

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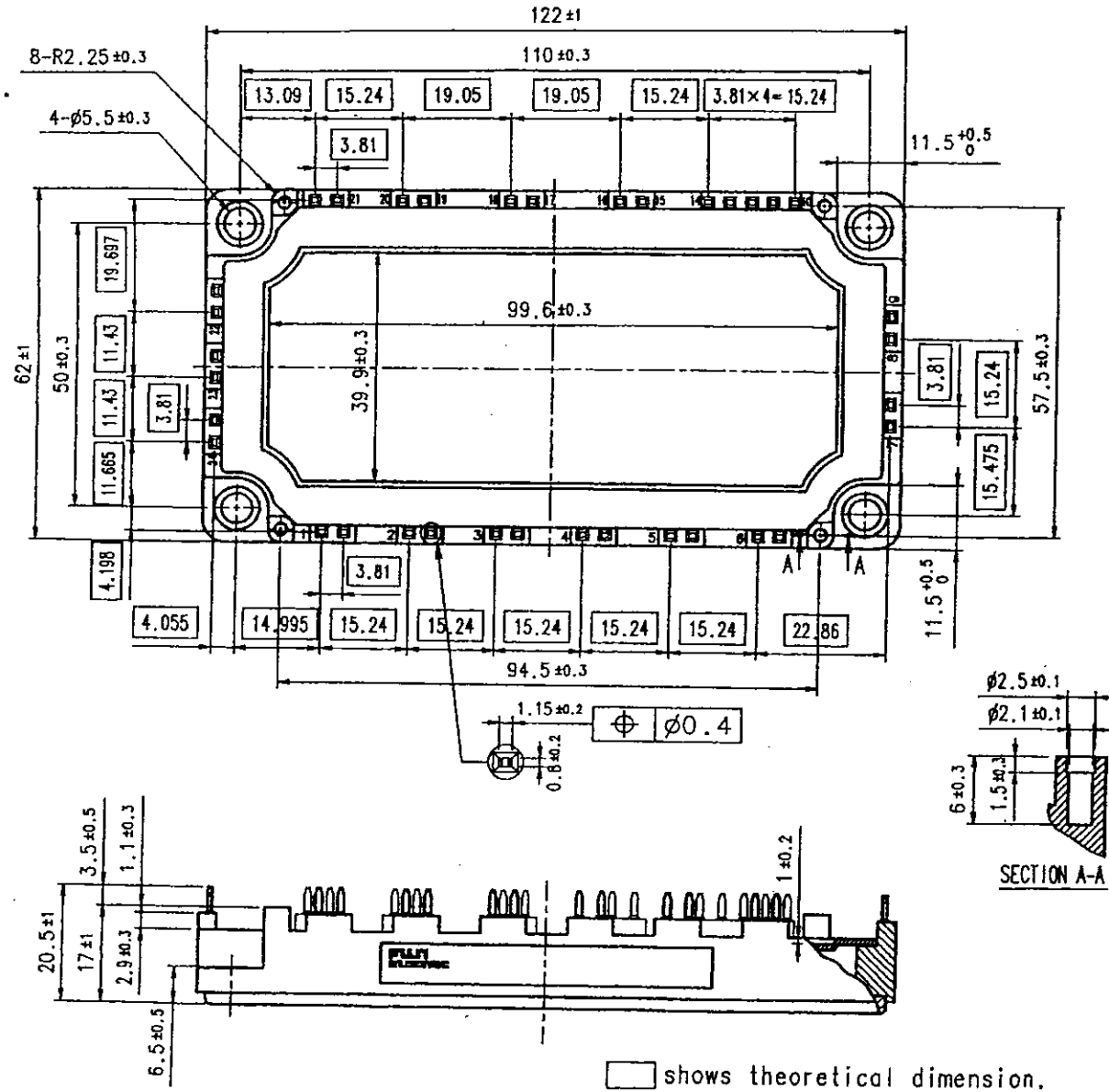
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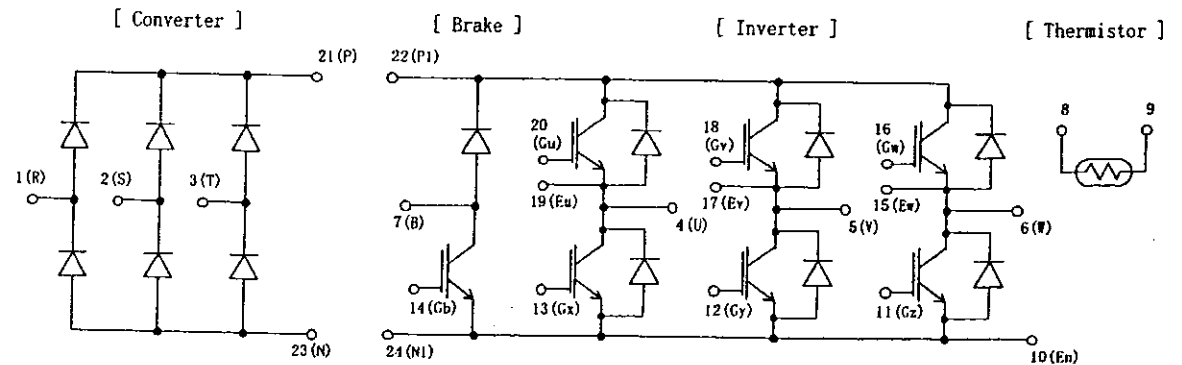
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7MBR35SB120-01

1. Outline Drawing (Unit : mm)



2. Equivalent circuit



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MS6M 0554

3/10

H04-004-03

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3. Absolute Maximum Ratings (at Tc= 25C unless otherwise specified)

Items		Symbols	Conditions		Maximum Ratings	Units
Inverter	Collector-Emitter voltage	VCES			1200	V
	Gate-Emitter voltage	VGES			+20	V
	Collector current	Ic	Continuous	Tc=25C	50	A
				Tc=80C	35	
		Icp	1ms	Tc=25C	100	A
				Tc=80C	70	
	-Ic			35	A	
Collector Power Dissipation	Pc	1 device		240	W	
Brake	Collector-Emitter voltage	VCES			1200	V
	Gate-Emitter voltage	VGES			+20	V
	Collector current	Ic	Continuous	Tc=25C	35	A
				Tc=80C	25	
		Icp	1ms	Tc=25C	70	A
				Tc=80C	50	
	Collector Power Dissipation	Pc	1 device		180	W
Repetitive peak reverse Voltage(Diode)	VRRM			1200	V	
Converter	Repetitive peak reverse Voltage	VRRM			1600	V
	Average Output Current	Io	50Hz/60Hz sine wave		35	A
	Surge Current (Non-Repetitive)	IFSM	Tj=150C,10ms		360	A
	I ² t (Non-Repetitive)	I ² t	half sine wave		648	A ² s
	Junction temperature	Tj			150	C
Storage temperature		Tstg			-40~ +125	C
Isolation voltage	between terminal and copper base ⁽¹⁾	Viso	AC : 1min.		2500	V
	between thermistor and others ⁽²⁾				2500	V
Mounting Screw Torque ⁽³⁾					3.5	Nm

(*)1 All terminals should be connected together when isolation test will be done.

(*)2 Terminal 8 and 9 should be connected together. Terminal 1 to 7 and 10 to 24 should be connected together and shorted to copper base.

(*)3 Recommendable Value : 2.5~3.5 Nm (M5)

MS6M 0554

4/10

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4. Electrical characteristics (at Tj= 25C unless otherwise specified)

	Items	Symbols	Conditions	Characteristics			Units
				min.	typ.	Max.	
Inverter	Zero gate voltage Collector current	ICES	VGE = 0 V, VCE= 1200 V			1.0	mA
	Gate-Emitter leakage current	IGES	VCE = 0 V, VGE= +20 V			200	nA
	Gate-Emitter threshold voltage	VGE(th)	VCE = 20 V, Ic = 35 mA	5.5	7.2	8.5	V
	Collector-Emitter saturation voltage	VCE(sat)	VGE = 15 V, chip		2.1		V
			Ic = 35 A terminal		2.25	2.7	
	Input capacitance	Cies	VGE = 0 V, VCE= 10 V f = 1 MHz		4200		pF
	Turn-on time	ton	Vcc= 600 V		0.35	1.2	us
		tr	Ic = 35 A		0.25	0.6	
		trθ	VGE = +15 V		0.1		
	Turn-off time	toff	RG = 33 ohm		0.45	1.0	
		tf			0.08	0.3	
	Forward on voltage	VF	IF = 35 A chip		2.3		V
			terminal		2.45	3.3	
	Reverse recovery time	trr	IF = 35 A			350	ns
Brake	Zero gate voltage Collector current	ICES	VGE = 0 V, VCE= 1200 V			1.0	mA
	Gate-Emitter leakage current	IGES	VCE = 0 V, VGE= +20 V			200	nA
	Collector-Emitter saturation voltage	VCE(sat)	VGE = 15 V, chip		2.1		V
			Ic = 25 A terminal		2.25	2.7	
	Turn-on time	ton	Vcc= 600 V		0.35	1.2	us
		tr	Ic = 25 A		0.25	0.6	
	Turn-off time	toff	VGE = +15 V		0.45	1.0	
		tf	RG = 51 ohm		0.08	0.3	
	Reverse current	IRRM	VR = 1200 V			1.0	mA
Converter	Forward on voltage	VFM	IF = 35 A chip		1.1		V
			terminal		1.2	1.5	
	Reverse current	IRRM	VR = 1600 V			1.0	mA
Thermistor	Resistance	R	T = 25C		5000		ohm
			T = 100C	465	495	520	
	B value	B	T = 25/50C	3305	3375	3450	K

5. Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	Max.	
Thermal resistance (1 device)	Rth(j-c)	Inverter IGBT			0.52	C/W
		Inverter FWD			0.90	
		Brake IGBT			0.69	
		Converter Diode			0.75	
Contact Thermal resistance	Rth(c-f)	with Thermal Compound (*)		0.05		C/W

* This is the value which is defined mounting on the additional cooling fin with thermal compound.

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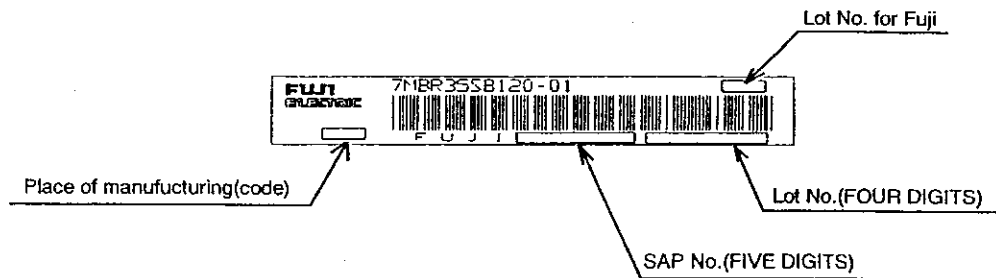
MS6M 0554

5 / 10

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H04-004-03

6. Indication on module



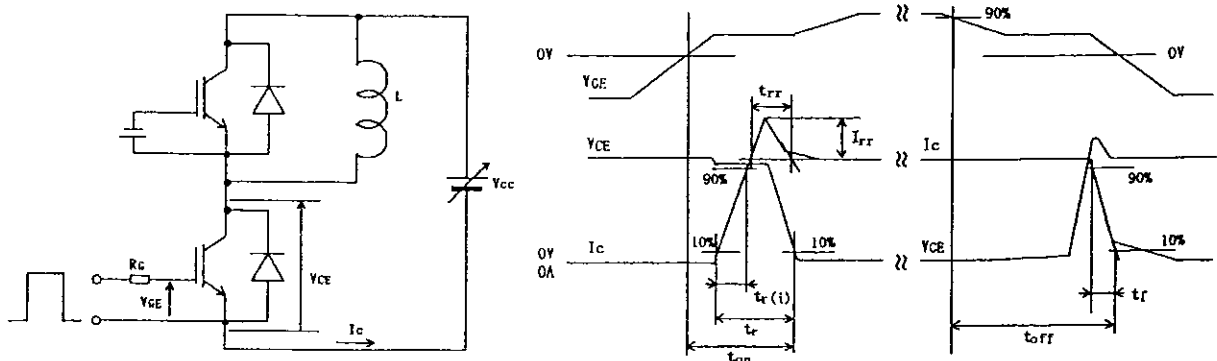
7. Applicable category

This specification is applied to Power Integrated Module named 7MBR35SB120-01.

8. Storage and transportation notes

- The module should be stored at a standard temperature of 5 to 35°C and humidity of 45 to 75%.
- Store modules in a place with few temperature changes in order to avoid condensation on the module surface.
- Avoid exposure to corrosive gases and dust.
- Avoid excessive external force on the module.
- Store modules with unprocessed terminals.
- Do not drop or otherwise shock the modules when transporting.
- Please connect adequate fuse or protector of circuit between three-phase line and this product to prevent the equipment from causing secondary destruction.

9. Definitions of switching time



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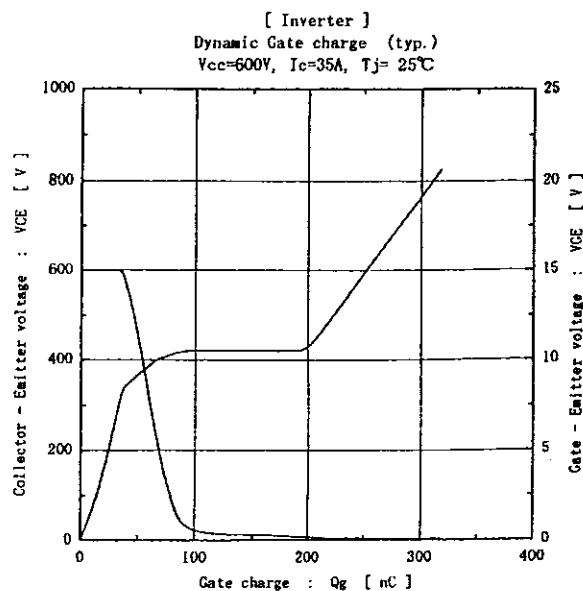
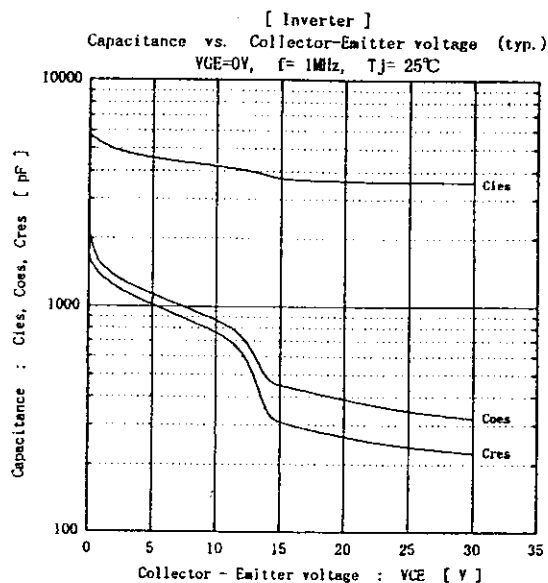
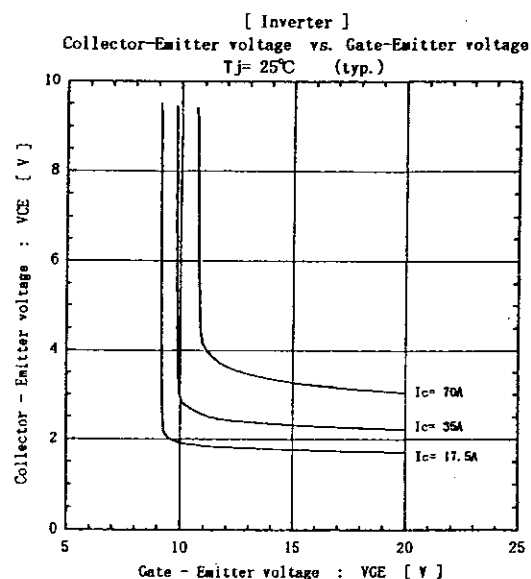
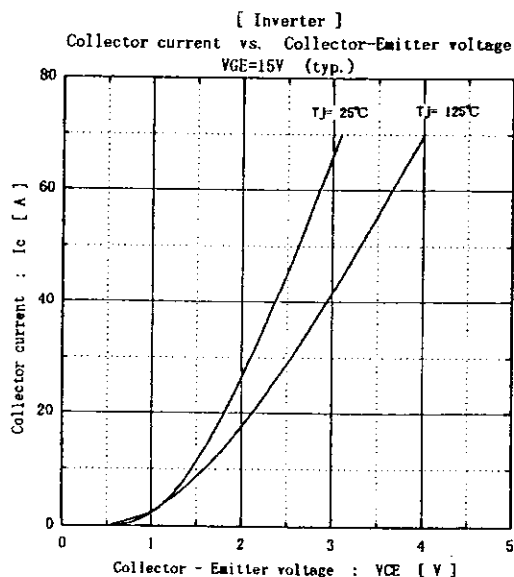
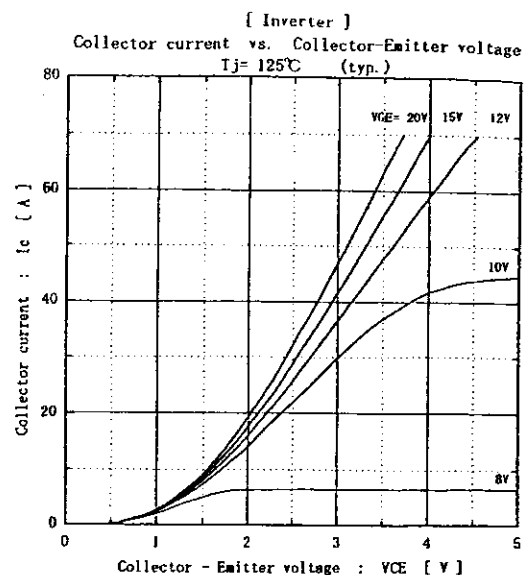
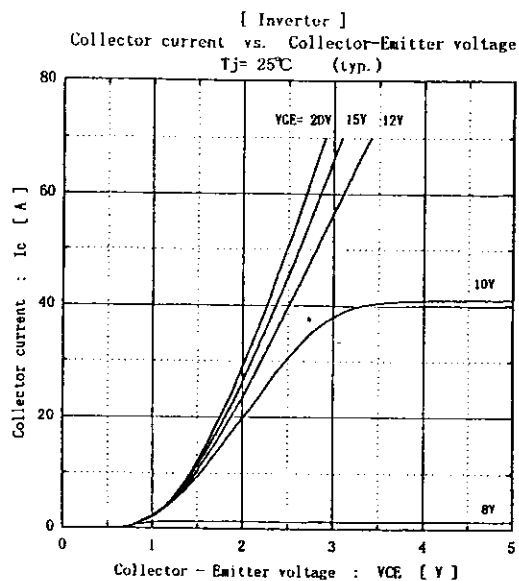
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6 / 10

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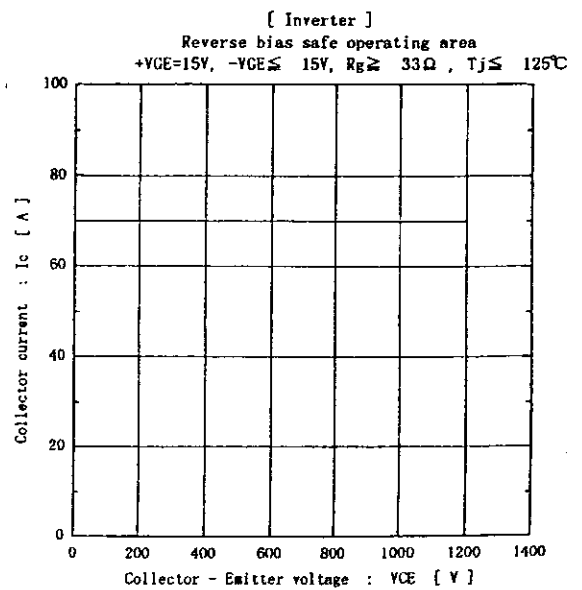
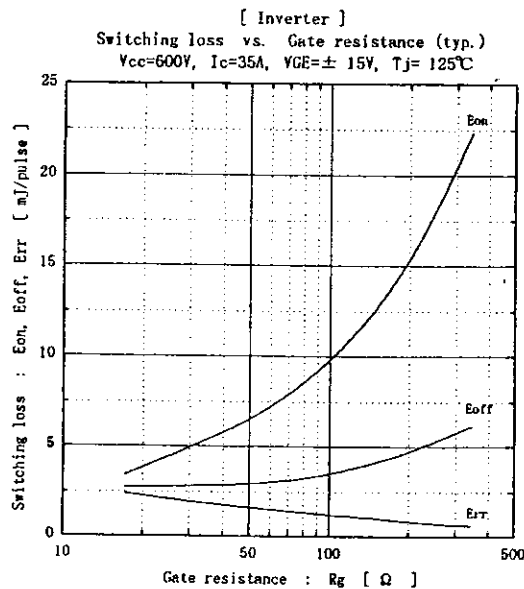
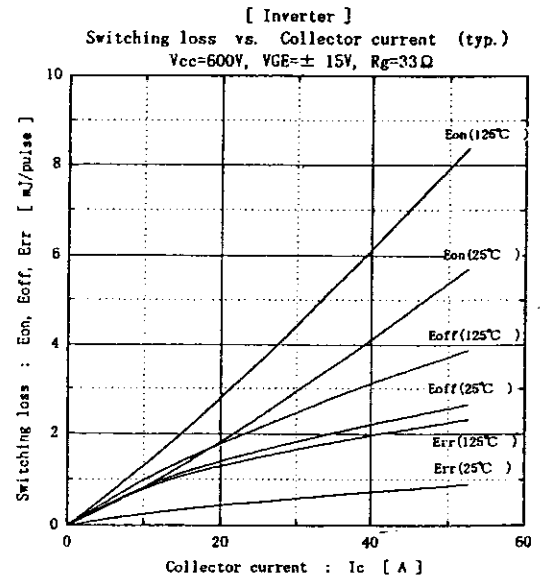
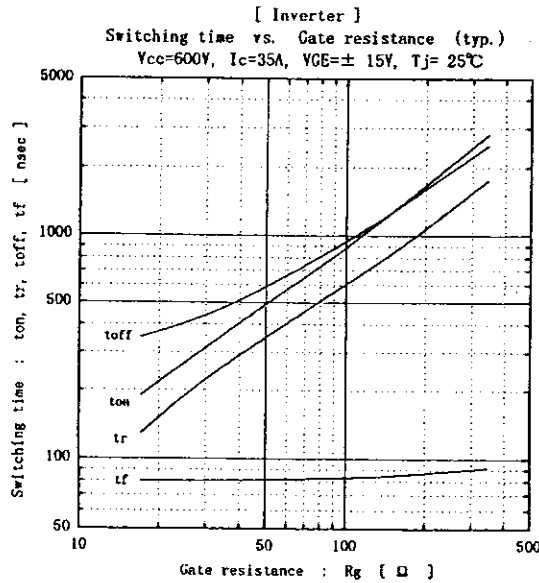
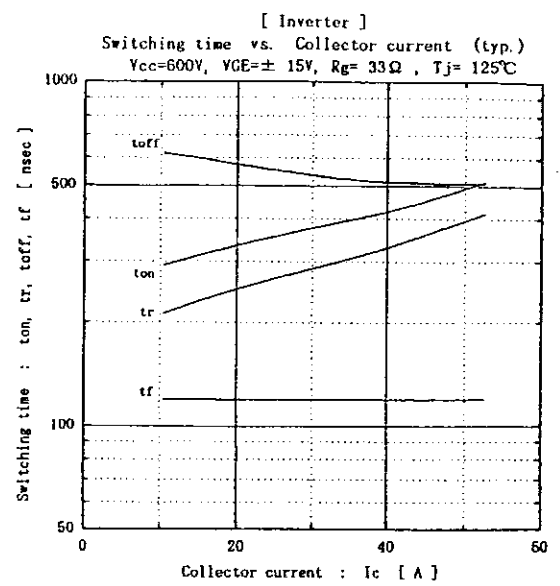
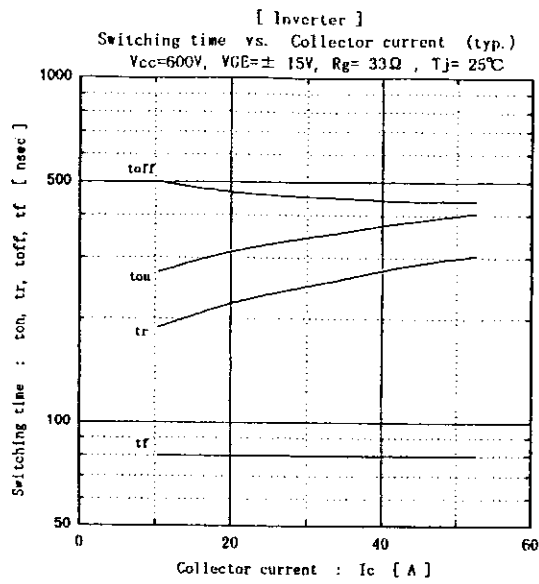
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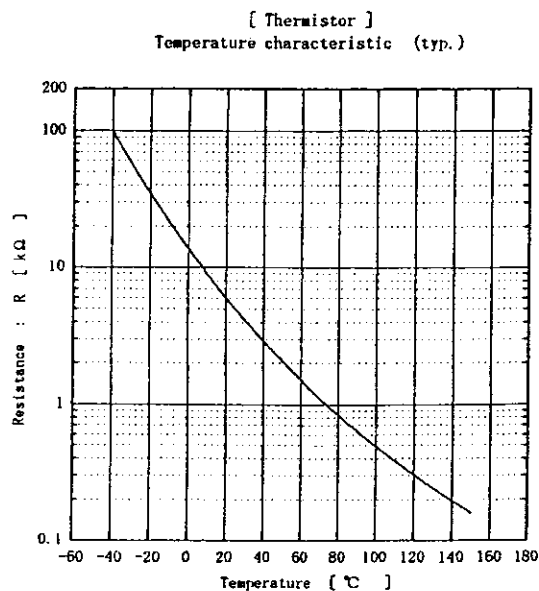
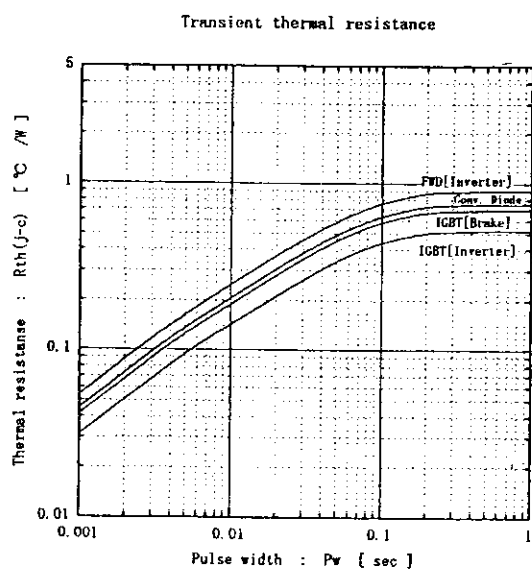
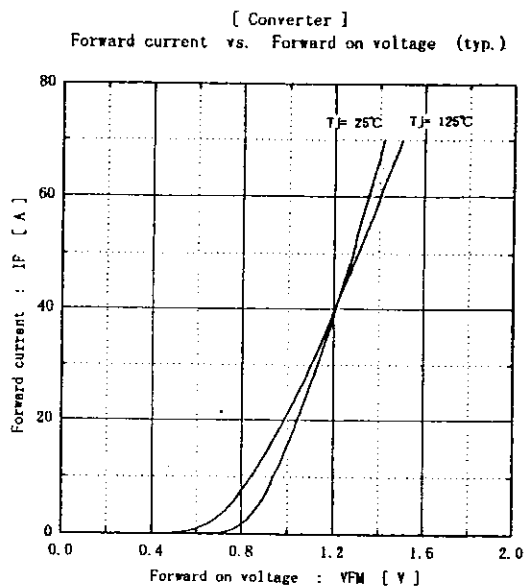
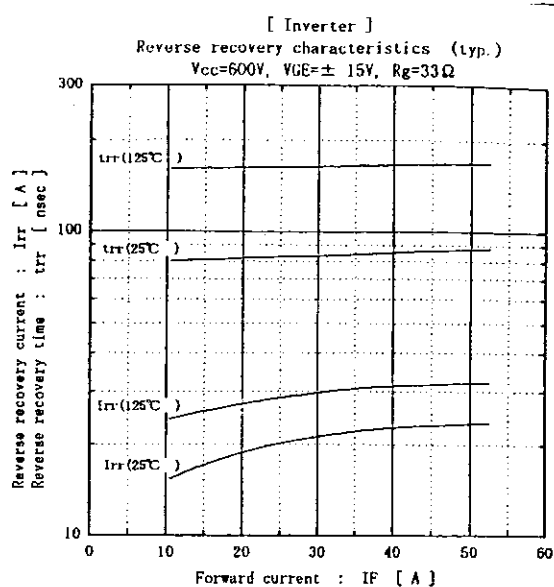
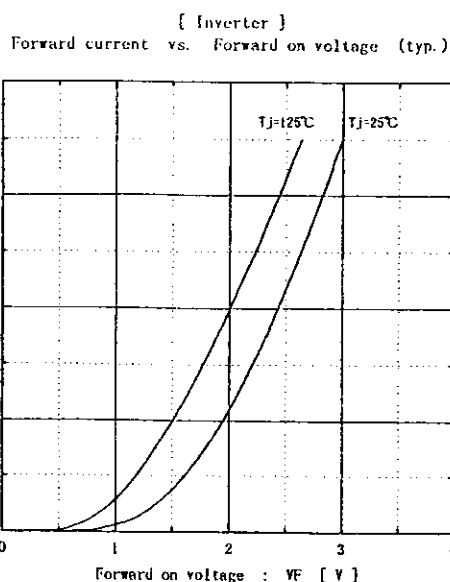
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8/10

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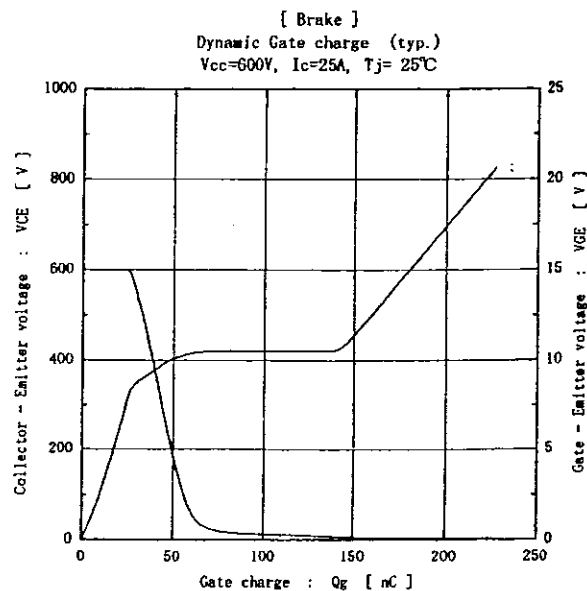
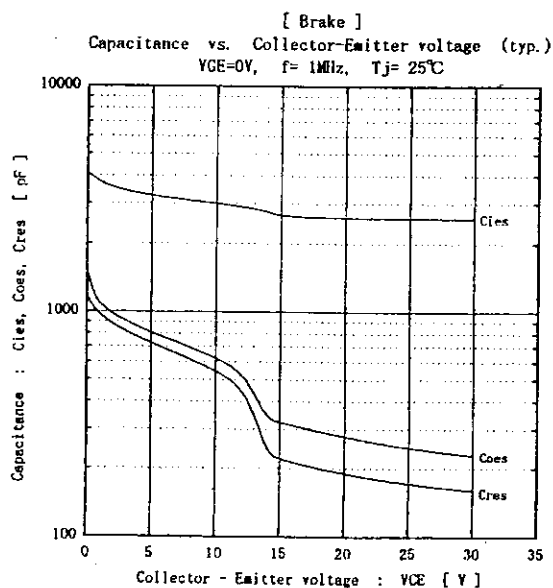
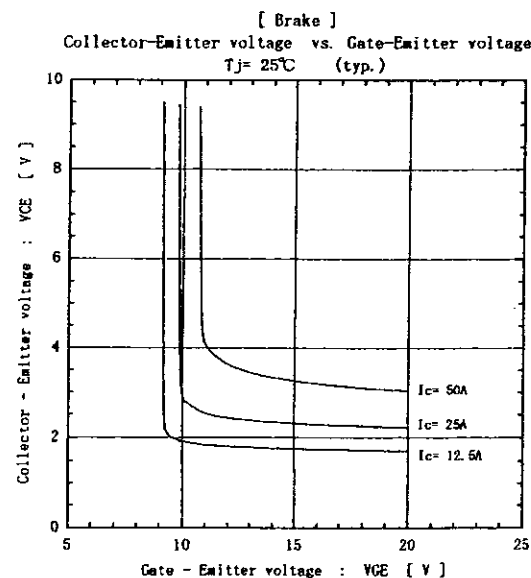
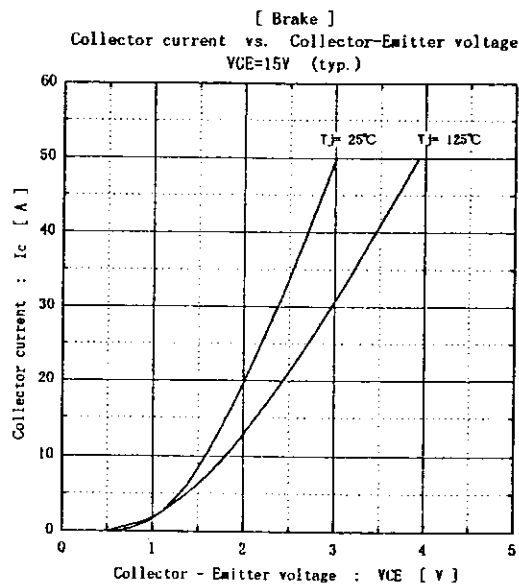
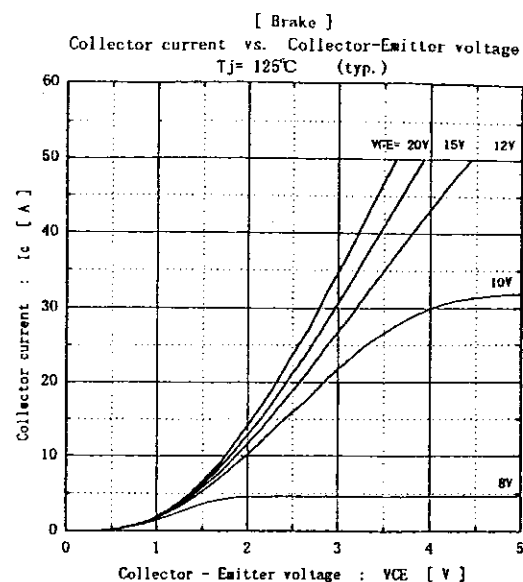
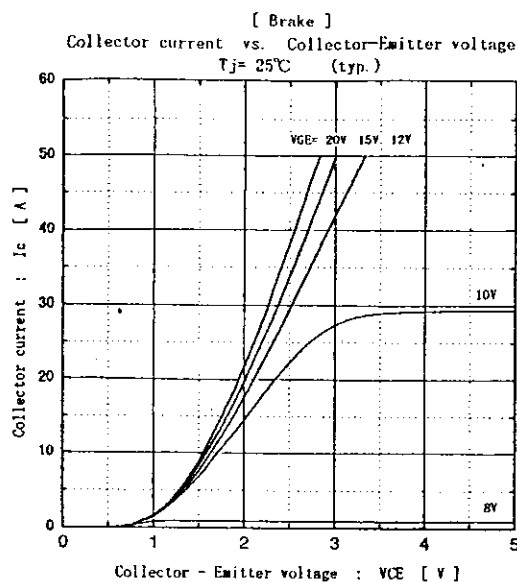
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9 / 10

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